A DUAL-BAND 3-BIT RECONFIGURABLE INTELLIGENT SURFACE WITH INDEPENDENT CONTROL OF PHASES

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Abstract – Reconfigurable Intelligent Surfaces (RISs) have received a great deal of attention from the wireless communication community due to their powerful ability to improve the wireless communication environment. Dual-band RIS enables aperture to share two bands, improving spectrum utilization in wireless communications and thus expanding communication capacity. However, most of the reported dual-band RISS cannot achieve independent controls of the dual-band phases, which greatly limits their practical application in wireless communications. In this paper, we propose a dual-band 3-bit RIS to achieve independent controls of the reflection phases in two frequency bands by designing two tunable structures without raising the profile. It also exhibits low sensitivity to incident angles between 0° and 50°. Thereafter, the beam steering ability of the proposed RIS is further investigated with experiments under normal and oblique incidences at two frequencies, which demonstrates the powerful potential of RISs to manipulate the electromagnetic wave propagation environment.

Keywords – Angular stability, beam steering, dual-band, reconfigurable intelligent surface

1. INTRODUCTION

Future wireless communications are featured by increasing the demands for communication speed, capacity and stability. Originating from programmable and information metasurfaces [1, 2, 3, 4, 5, 6], reconfigurable intelligent surfaces (RISs) are widely recognized as one of the most promising frontier technologies for next-generation wireless communications because of their ability to flexibly modulate Electromagnetic (EM) waves [7, 8, 9, 10] in real time, including the amplitude [11], phase [12], polarization [13] and frequency [14]. They enable active and intelligent controls of the EM environment, thereby breaking the inherent notion that wireless channels are randomly uncontrollable [15, 16].

Multichannel signals are transmitted independently and simultaneously in the same wireless environment by manipulating the EM waves independently on two or more frequency bands, thus increasing the communication capacity without enlarging the RIS aperture size [17, 18]. Some approaches on dual-band RISSs [17, 19, 20, 21] have been proposed, but their reflection phases cannot be independently modulated on both bands. Hence such dual-band RISSs cannot fully exploit their advantages in wireless communications. A 1-bit dual-band RIS element loaded with two PIN diodes in different layers has been proposed in [22]. However, the longer bit-width RISSs can achieve finer manipulation of EM waves and higher wireless channel capacity [12, 23]. In addition, the potential phase distortion caused by different incidence angles also needs to be considered, since it is difficult to obtain a normal incidence scenario in the real wireless communication environment [16, 24].

In this paper, a dual-band 3-bit RIS is proposed to achieve independent control of the reflection phase in two frequency bands (FB1=2.52-2.67 GHz, FB2=3.4-3.5 GHz). The angular stability of the RIS has been improved by designing numerous metallic vias between the elements. Beam steering is performed to demonstrate the ability of our proposed RIS to manipulate the far-field EM wave distribution. In addition, the scattering patterns are investigated at two frequencies for both normal and oblique incidences. Finally, the measurement results of the fabricated prototype are in good agreement with the theoretical and simulation
results. The proposed dual-band RIS has a powerful ability in EM wave manipulation, thereby possessing great potential for future RIS-assisted wireless communication.

2. THE DESIGN PROCEDURE AND SIMULATION OF THE RIS ELEMENT

Fig. 1 shows the structure of the proposed dual-band RIS element. It is composed of three metal layers and two dielectric slabs (F4B, \( \varepsilon_r = 2.65 \), \( \tan \delta = 0.003 \)) with a thickness of \( h_1 \) (3.3 mm) and \( h_2 \) (0.2 mm), respectively. The top metal layer consists of two different pairs of metal patches, each of which is connected by a varactor to realize EM wave manipulation in different frequency bands. The design of the rectangular patches in the RIS element is inspired by [12] and [22]. The dimensions of the

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**Fig. 1** - Sketch of the proposed (a) RIS and (b) the top view and (c) the explosive view of the RIS element

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**Fig. 2** - The equivalent capacitance of the varactor and the reflection phase varies with biasing voltage

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**Fig. 3** - The simulated reflection spectrum of the RIS element at normal incidence. (a) Amplitude and (b) phase spectrum operating in FB1 (2.52-2.67 GHz). (c) Amplitude and (d) phase spectrum operating in FB2 (3.4-3.5 GHz)
Rectangular patches can be easily adjusted to optimize the EM characteristics of the RIS. At the resonant frequency, the induced current is excited on the surface of the rectangular patches and flows through the varactor, thus allowing the varactor to control the scattering field. The varactor (Skyworks 1405-079LF) can be modeled as a series circuit of a tunable capacitor ($C_{var} = 0.66$–2.6 pF), a resistor ($R_{var} = 0.7$ Ω), and an inductor ($L_{var} = 0.7$ nH). The varactor with a small equivalent resistance is selected to reduce the ohmic loss, whose equivalent capacitance can be varied with the biasing voltage, as shown in Fig. 2. The middle metal layer acts as a reflecting plate; meanwhile, it also connects to the patches through metallic vias to work as the Direct Current (DC) ground. The two bottom feeding lines are connected to the surface patches to provide independent control voltages for varactors. Since each feeding line connects all the elements along the $x$-axis direction, it leads to them working in the same state. Numerous metallic vias are designed in the upper substrate along the $x$-axis to suppress the adjacent coupling effect and form a more stable EM wave propagation mode, thus reducing the dependence of the incident angles, as described in [12].

During the simulation, the commercial EM calculation software, CST Microwave Studio 2019, is used to calculate the reflection coefficient of the RIS element under plane wave illumination. The unit cell boundaries are set on the $x$ and $y$ axes to simulate an infinite array, which considers the mutual coupling between the adjacent elements. The Floquet port is set above the element to excite $y$-polarized plane waves.

Fig. 3 shows the reflection amplitude and phase of the RIS element under different biasing voltages at normal incidence. The blue and yellow bars respectively represent the two bands independently controlled by varactor1 (Var1) and varactor2 (Var2). For example, when the voltage on Var2 is fixed (0 V), the reflection phase in FB1 will vary with the voltage on Var1, while the reflection phase in FB2 remains stable, as shown in Fig. 3(b); and vice versa Fig. 3(d) shows that the reflection phase in FB2 only depends on the control voltages on Var2. In addition, a reflection amplitude above ~3 dB can be achieved under different biasing voltages, as shown in Fig. 3(a) and Fig. 3(c).

A phase-shifting RIS can be defined as an $n$-bit quantized RIS that has $2^n$ coding states with phase shifting intervals of $360°/2^n$ [1]. The designed RIS element has the capability of continuous phase shifting in both FB1 and FB2 with the maximum phase shifting range exceeding 315°, thereby evolving into a dual-band 3-bit RIS. Table 1 lists the required biasing voltages for the coding states (“0, 1, 2,..., 7”) in two frequency bands FB1 and FB2, respectively.

### Table 1 – The 3-bit coding states and corresponding voltages of the varactors

<table>
<thead>
<tr>
<th>Coding States</th>
<th>0</th>
<th>1</th>
<th>2</th>
<th>3</th>
<th>4</th>
<th>5</th>
<th>6</th>
<th>7</th>
</tr>
</thead>
<tbody>
<tr>
<td>Voltage (V) on Var1</td>
<td>0</td>
<td>-1.8</td>
<td>-2.5</td>
<td>-3</td>
<td>-3.5</td>
<td>-4</td>
<td>-5.5</td>
<td>-30</td>
</tr>
<tr>
<td>Phase shift in FB1 (2.52-2.67 GHz)</td>
<td>0°</td>
<td>45°</td>
<td>90°</td>
<td>135°</td>
<td>180°</td>
<td>225°</td>
<td>270°</td>
<td>315°</td>
</tr>
<tr>
<td>Voltage (V) on Var2</td>
<td>0</td>
<td>-4</td>
<td>-6</td>
<td>-7</td>
<td>-8</td>
<td>-9</td>
<td>-12</td>
<td>-30</td>
</tr>
<tr>
<td>Phase shift in FB2 (3.4-3.5 GHz)</td>
<td>0°</td>
<td>45°</td>
<td>90°</td>
<td>135°</td>
<td>180°</td>
<td>225°</td>
<td>270°</td>
<td>315°</td>
</tr>
</tbody>
</table>

**Fig. 4** – The surface current distribution of state ‘3’ on the patches in (a) FB1 and (b) FB2
To explain the working mechanism of the designed dual-band RIS element, field monitors are set respectively at 2.6 GHz and 3.4 GHz in the numerical simulation to observe the distribution of the surface current $J_s$. Fig. 4(a) and Fig. 4(b) show the surface current distribution of state ‘3’ on the patches in FB$_1$ and FB$_2$, respectively. It can be observed that $J_s$ is mainly concentrated near Var1 when the element operates in FB$_1$, while $J_s$ is mainly concentrated near Var2 when the element operates in FB$_2$. This allows the varactors to control the EM wave reflection independently in the dual bands.

In the actual wireless communication environment, both users and base stations are usually located away from the RIS normal, indicating that oblique incidence is more common. However, when oblique incidence occurs, the distortion of the reflection phase and amplitude caused by the incident angle may lead to performance deterioration of the RIS-assisted wireless communication system. In addition, it has been pointed out that the angle-dependent RIS may lead to non-reciprocity between the incident and reflected angles [16, 24]. Therefore, the robustness of RIS EM responses to the incident angle is a very important indicator to measure the performance of the RIS-assisted wireless communication system.

To demonstrate the angular property of the element, the reflection spectrum at a TM oblique incidence of 50° is further studied. As shown in Fig. 5, in the two separate operating bands, the reflection amplitudes of -3 dB or more can still be achieved, as well as the eight coding states with equal phase differences. Compared with Fig. 3, the reflection responses show low sensitivity to the incident angle. However, they still deteriorate when the incident angle becomes large. In fact, the performance of RIS at larger incidence angles will be influenced by many factors. For example, the limited aperture and the truncated boundary effect of the RIS make it unsuitable to work at a large oblique incident angle. For a TE polarized oblique incidence, we can also obtain angular stability from 0° to 50°. However, since the metallic vias parallel to the x-axis has no effect on the TE oblique incidence, the stability of the reflection coefficient is slightly worse for the TE oblique incidence than for the TM oblique incidence.

3. BEAM STEERING OF THE RIS

When an extra phase gradient is generated on the RIS interface, the EM wave will be abnormally reflected. According to the generalized Snell’s law [25], the reflection angle is determined by the phase gradient, incidence angle and operating frequency:

$$\theta_r = \sin^{-1}(\frac{\lambda_0}{2\pi} \cdot \frac{d\phi}{dx} + \sin \theta_i) \quad (1)$$

where $\theta_i$ and $\theta_r$ are the incidence and reflection angles with respect to the RIS normal, respectively. $\lambda_0$ is the wavelength of the EM wave in vacuum, $\frac{d\phi}{dx}$ is the phase gradient along the RIS interface. For the RIS with a finite size, we employ the scattering patterns to accurately analyze the distribution of EM waves in the far field [25, 26]:

$$f(\theta) = \sum_n f_n(\theta) \cdot e^{-j\varphi_0} \cdot e^{-j\frac{2\pi df}{\lambda_0} \left(\frac{n-1}{2}\right)(\sin \theta_i + \sin \theta)} \quad (2)$$
where $N$ is the column number of the RIS, $f_n(\theta)$ is the scattering pattern of the $n$-th element, which is approximated by a cosine function ($f_n(\theta) \approx \cos \theta$) [26]. $\varphi_0$ is the scattering phase of the $n$-th element, $d$ is the period of the RIS element. Equations (1) and (2) demonstrate the modulation principle of the reflected beam by changing the coding pattern on the RIS.

To investigate the beam steering capability of the RIS, the scattering patterns of the array composed of 8×11 elements are simulated by CST and calculated using Eq. (2). The coding sequence on the RIS is set to be “01234567” along the y-axis direction. The coding states and corresponding voltage can be found in Table 1.

As shown in Fig. 6(a), when the 2.6 GHz EM wave is normally incident on the RIS, a large lobe appears near 26.5°. This means that most of the incident energy is reflected to 26.5° by the coded RIS. When the EM wave incident is from 26.5°, the same phase gradient reflects the beam back to 0°, as shown in Fig. 6(b). The reciprocity of incident and reflection angles ensures the reciprocity of the wireless channel, which is the foundation of some wireless communication systems, such as a TDD wireless communication network [24]. The reciprocity of a wireless channel ensures the alignment of uplink and downlink in data transmission. The case of a large-angle oblique incidence has also been further considered. When the EM wave incident is from 50°, the reflected angle is −17.8°, as shown in Fig. 6(c). And when the EM wave incident is from −17.8°, the reflected angle is back to 50° again, as illustrated in Fig. 6(d). At the oblique incidence, the angular reciprocity of incidence and reflection still holds, which is attributed to the low angular sensitivity of the designed RIS element.
The same coding sequence "01234567" is investigated at 3.4 GHz. The corresponding 1D scattering patterns are presented in Fig. 7. Similar beam steering simulations with different oblique incidence angles confirm the angular reciprocity again. The normal incident EM waves are reflected to 21°, and the EM wave incident from 21° also returns to 0°; the EM wave incident from 50° is reflected to −25.5°, while the EM wave incident from −25.5° is reflected to 50°, consistent with the theoretical calculations.

4. FABRICATION AND MEASUREMENTS

To verify the performance of the designed RIS, a prototype is manufactured, as shown in Fig. 8. It is composed of 8×11 elements and the total size is 248×429 mm². A corresponding control circuit board is designed and fabricated to provide the biasing voltages for the varactors.

![Fig. 10](image1.png)  
**Fig. 10** – The measured reflection spectrum of the RIS element at normal incidence. (a) Amplitude and (b) phase spectrum working in FB₁, (c) Amplitude and (d) phase spectrum working in FB₂

![Fig. 11](image2.png)  
**Fig. 11** – The measured reflection spectrum of the RIS element at TM oblique incidence of 50°. (a) Amplitude and (b) phase spectrum working in FB₁, (c) Amplitude and (d) phase spectrum working in FB₂

![Fig. 12](image3.png)  
**Fig. 12** – Measurement configuration of scattering patterns
The reflection coefficient spectrum is measured in a microwave anechoic chamber, as shown in Fig. 9. Two horn antennas are symmetrically placed on both sides of the RIS normal to excite and receive EM waves, respectively. A Vector Network Analyzer (VNA, Agilent N5245A) connects the antennas by RF cables. The reflection coefficient can be further obtained by normalizing the reflection signal to that of a metal plate of the same size as the RIS.

Fig. 10 and Fig. 11 show the measurement results at normal incidence and TM 50° oblique incidence, respectively. 3-bit coding can be realized in both FB1 and FB2 to achieve independent control of the reflection phase for both normal and oblique incidence. When normally the EM wave incident on the RIS, the reflection amplitude in FB1 and FB2 is greater than −5 dB. While at the incidence of 50°, it shows a slight distortion, which is due to the limited aperture and the truncated boundaries of RIS, as discussed above.

The experimental environment of a scattering pattern measurement is demonstrated in Fig. 12. The RIS and the transmitting antenna are placed on a rotating platform. The transmitting antenna is connected to the analog signal generator (Agilent E8257D) and the receiving antenna is connected to the signal analyzer (Agilent N9010A). When the rotating platform drives the RIS and the transmitting antenna to rotate together, the signal intensity at different receiving angles is measured and recorded. The measured 1D scattering patterns are shown in solid blue lines in Fig. 6 (FB1) and Fig. 7 (FB2), demonstrating good agreements with the theoretical and simulated ones.

It should be noted that due to the large incidence angle and the limited RIS aperture, part of the excited EM wave energy is received directly through the line of sight path. The reflection signal superimposes the diffraction signal, which results in ripples in the side lobes of the measured scattering patterns.

Table 2 compares the performance of the proposed RIS element with several early reported RIS designs. Most of the reported dual-band RISs cannot achieve independent modulation of the phase on both bands, except for the one reported in [22]. In addition, the proposed RIS also features a wider bit width and better robustness to the incident angle compared to other work.

5. CONCLUSION

In this paper, a 3-bit RIS with independent control of a phase over dual bands is proposed. By designing two pairs of metal patches of different sizes in one element and loading two varactors on them, independent phase control of the reflected waves in two frequency bands is achieved. The simulation result shows that the induced currents are distributed at different locations in the two frequency bands, which explains the mechanism of independent control of dual-band reflection phases. Numerous metallic vias between adjacent elements are designed to improve the angular stability so that it can perform well in the incident angle range of 0°-50°. The simulation and measurement results of the scattering patterns at normal and oblique incidence are all in good agreement with the theoretical ones. The good performance of the proposed dual-band RIS provides a potential solution to further expand the communication capacity of RIS-based wireless communication systems.

REFERENCES

Liang et al.: A dual-band 3-bit reconfigurable intelligent surface with independent control of phases


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